Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-2585

Inclosure Material:	
Metal	
Overall Length:	
Between 0.115 inches and 0.150 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Desig	nation:
To-52	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
45.0 collector to base voltage/static/emitter open all transistor and 45.0 co	llector to emitter voltage/static/base open all transistor and 6.0
emitter to base voltage, static, collector open all transistor	
Current Rating Per Characteristic:	
20.00 milliamperes source cutoff current all transistor	
Power Rating Per Characteristic:	
500.0 milliwatts small-signal input power, common-collector preset all tran	sistor
Maximum Operating Tempurature Per Measurement Point:	
125.0 degrees celsius junction	
Special Features:	
Internal junction configutation transistor pnp	
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
-	
Demilitarization:	
No	
Fiig:	
A110a0	